

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC2500

Strobe Flash Applications

Medium-Power Amplifier Applications

Unit: mm

- High DC current gain and excellent h_{FE} linearity
 $h_{FE} (1) = 140$ to 600 ($V_{CE} = 1$ V, $I_C = 0.5$ A)
 $h_{FE} (2) = 70$ (min), 200 (typ.), ($V_{CE} = 1$ V, $I_C = 2$ A)
- Low saturation voltage: $V_{CE(sat)} = 0.5$ V (max) ($I_C = 2$ A, $I_B = 50$ mA)

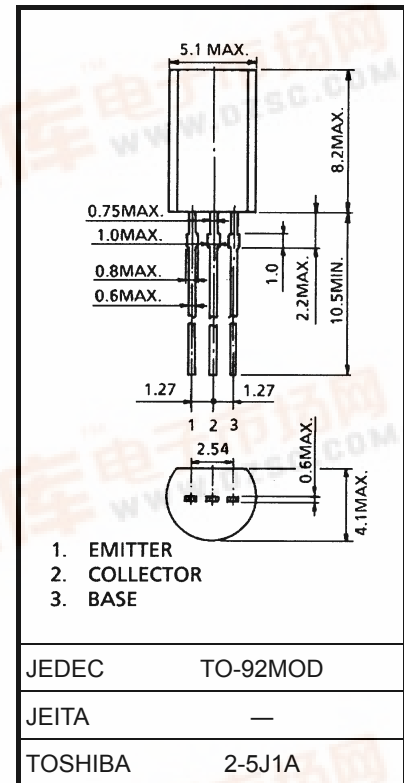
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	30	V
Collector-emitter voltage		V_{CES}	30	V
		V_{CEO}	10	
Emitter-base voltage		V_{EBO}	6	V
Collector current	DC	I_C	2	A
	Pulsed (Note 1)	I_{CP}	5	
Base current		I_B	0.5	A
Collector power dissipation		P_C	900	mW
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note 1: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).



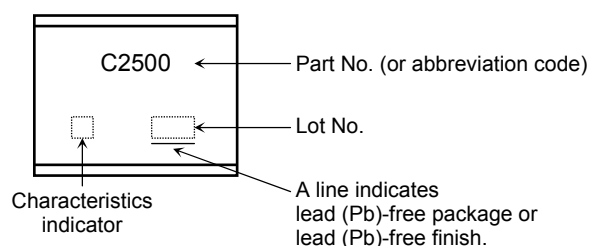
Weight: 0.36 g (typ.)

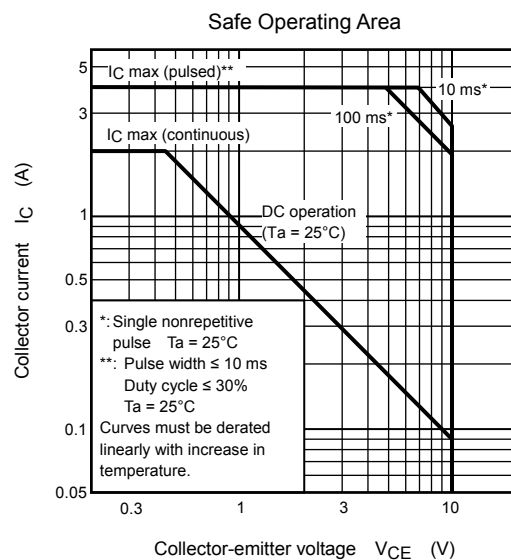
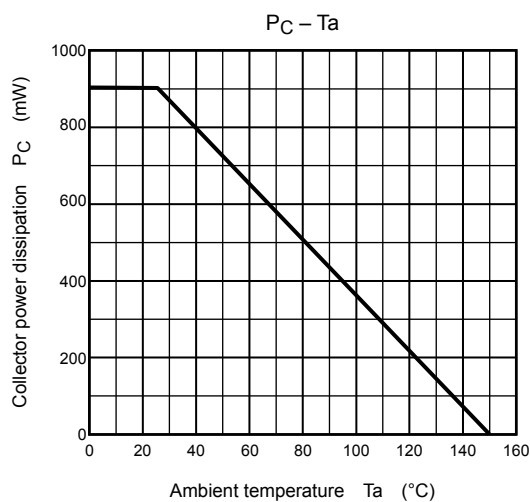
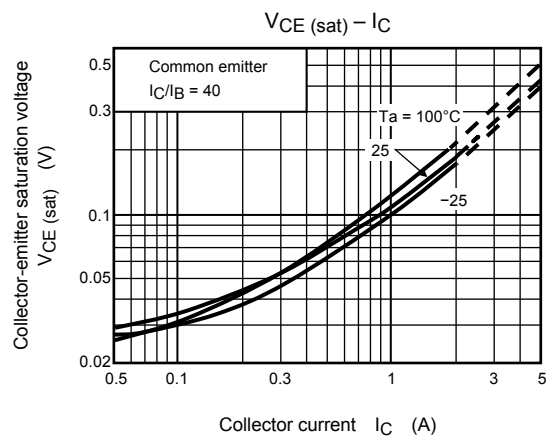
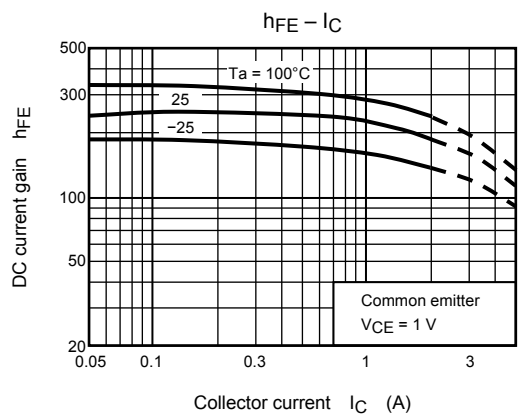
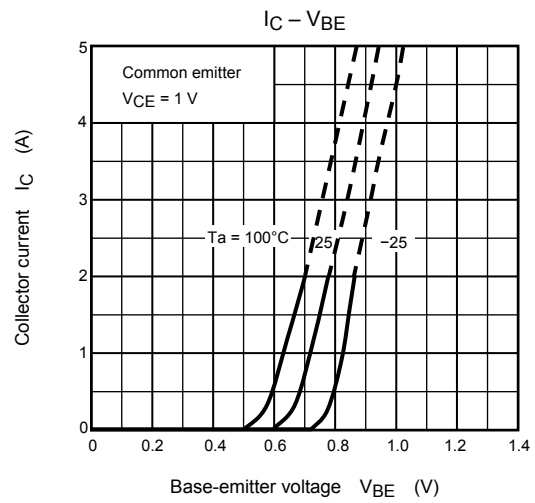
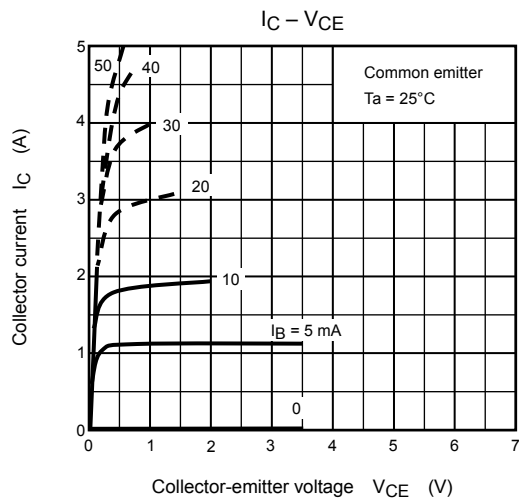
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB} = 30\text{ V}, I_E = 0$	—	—	100	nA
Emitter cut-off current	I_{EBO}	$V_{EB} = 6\text{ V}, I_C = 0$	—	—	100	nA
Collector-emitter breakdown voltage	V_{CEO}	$I_C = 10\text{ mA}, I_B = 0$	10	—	—	V
Emitter-base breakdown voltage	V_{EBO}	$I_C = 1\text{ mA}, I_C = 0$	6	—	—	V
DC current gain	$h_{FE(1)}$ (Note 3)	$V_{CE} = 1\text{ V}, I_C = 0.5\text{ A}$	140	—	600	
	$h_{FE(2)}$	$V_{CE} = 1\text{ V}, I_C = 2\text{ A}$	70	200	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 2\text{ A}, I_B = 50\text{ mA}$	—	0.2	0.5	V
Base-emitter voltage	V_{BE}	$V_{CE} = 1\text{ V}, I_C = 2\text{ A}$	—	0.86	1.5	V
Transition frequency	f_T	$V_{CE} = 1\text{ V}, I_C = 0.5\text{ A}$	—	150	—	MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	27	—	pF

Note 3: $h_{FE(1)}$ classification A: 140 to 240, B: 200 to 330, C: 300 to 450, D: 420 to 600

Marking





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20070701-EN

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